

## SOTiny™ Low Voltage Dual SPDT Analog Switch 2:1 Mux/DeMux Bus Switch

### Description

The DIODES PI5A3157 is a high-bandwidth, fast single-pole double-throw (SPDT) CMOS switch. It can be used as an analog switch or as a low-delay bus switch. Specified over a wide operating power supply voltage range, 1.65V to 5.5V, the PI5A3157 has a maximum ON resistance of 12Ω at 1.65V, 9Ω at 2.3V & 6Ω at 4.5V.

Break-before-make switching prevents both switches being enabled simultaneously. This eliminates signal disruption during switching.

The control input, S, tolerates input drive signals up to 5.5V, independent of supply voltage.

The PI5A3157 is an improved direct replacement for the NC-7SB3157.

### Application(s)

- Cell Phones
- PDAs
- Portable Instrumentation
- Battery Powered Communications
- Computer Peripherals

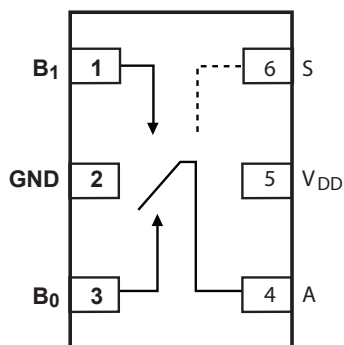
### Features

- CMOS Technology for Bus and Analog Applications
- Low On-Resistance: 8Ω at 3.0V
- Wide V<sub>DD</sub> Range: 1.65V to 5.5V
- Rail-to-Rail Signal Range
- Control Input Overvoltage Tolerance: 5.5V min.
- Fast Transition Speed: 5.2ns max. at 5V
- High Off Isolation: 57dB at 10MHz
- 54dB (10MHz) Crosstalk Rejection Reduces Signal Distortion
- Break-Before-Make Switching
- High Bandwidth: 250 MHz
- Extended Industrial Temperature Range: -40°C to 85°C
- Improved Direct Replacement for NC7SB3157
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>
- Packaging (Pb-free & Green available):
  - 6-pin SC70 (C)

#### Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Configuration/Connection Diagram



## Pin Description

| Pin Number | Pin Name        | Description                 |
|------------|-----------------|-----------------------------|
| 1          | B <sub>1</sub>  | Data port                   |
| 2          | GND             | Ground                      |
| 3          | B <sub>0</sub>  | Data port (Normally Closed) |
| 4          | A               | Common Output/Data port     |
| 5          | V <sub>DD</sub> | Positive Power Supply       |
| 6          | S               | Logic Control               |

## Logic Function Table

| Logic Input(s) | Function                       |
|----------------|--------------------------------|
| 0              | B <sub>0</sub> Connection to A |
| 1              | B <sub>1</sub> Connected to A  |

## Absolute Maximum Ratings<sup>(1)</sup>

|                                                          |                         |
|----------------------------------------------------------|-------------------------|
| Supply Voltage $V_{DD}$ .....                            | -0.5V to +7V            |
| DC Switch Voltage ( $V_S$ ) <sup>(2)</sup> .....         | -0.5V to $V_{DD}$ +0.5V |
| DC Input Voltage ( $V_{IN}$ ) <sup>(2)</sup> .....       | -0.5V to +7.0V          |
| DC Output Current ( $I_{OUT}$ ) .....                    | 128mA                   |
| DC $V_{DD}$ or Ground Current ( $I_{CC}/I_{GND}$ ) ..... | ±100mA                  |
| Storage Temperature Range ( $T_{STG}$ ) .....            | -65°C to +150°C         |
| Junction Temperature under Bias ( $T_J$ ) .....          | 125°C                   |
| Power Dissipation ( $P_D$ ) @ +85°C .....                | 180mW                   |

## Recommended Operating Conditions<sup>(3)</sup>

|                                             |                 |
|---------------------------------------------|-----------------|
| Supply Voltage Operating ( $V_{DD}$ ) ..... | 1.65V to 5.5V   |
| Control Input Voltage ( $V_{IN}$ ) .....    | 0V to $V_{DD}$  |
| Switch Input Voltage ( $V_{IN}$ ) .....     | 0V to $V_{DD}$  |
| Output Voltage ( $V_{OUT}$ ) .....          | 0V to $V_{DD}$  |
| Operating Temperature ( $T_A$ ) .....       | -40°C to +85°C  |
| Input Rise and Fall Time ( $t_{Btf}$ )      |                 |
| Control Input $V_{DD}$ = 2.3V - 3.6V .....  | 0ns/V to 10ns/V |
| Control Input $V_{DD}$ = 4.5V - 5.5V .....  | 0ns/V to 5ns/V  |
| Thermal Resistance ( $\theta_{JA}$ ) .....  | 350°C/W         |

### Notes:

1. Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
3. Control input must be held HIGH or LOW; it must not float.

## DC Electrical Characteristics

Over the Operating Temperature Range,  $T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$

| Parameters | Description                  | Test Conditions                                | Supply Voltage | Temp                                     | Min. | Typ. | Max.     | Units    |
|------------|------------------------------|------------------------------------------------|----------------|------------------------------------------|------|------|----------|----------|
| $V_{IAR}$  | Analog Input Signal Range    |                                                | $V_{DD}$       | $T_A = 25^\circ\text{C}$ & -40°C to 85°C | 0    |      | $V_{DD}$ | V        |
| $R_{ON}$   | On-Resistance <sup>(1)</sup> | $I_O = 30\text{mA}$ , $V_{IN} = 0\text{V}$     | 4.5V           | $T_A = 25^\circ\text{C}$                 |      | 4    | 6        | $\Omega$ |
|            |                              | $I_O = -30\text{mA}$ , $V_{IN} = 2.4\text{V}$  |                |                                          |      | 5    | 8        |          |
|            |                              | $I_O = -30\text{mA}$ , $V_{IN} = 4.5\text{V}$  |                |                                          |      | 8    | 13       |          |
|            |                              | $I_O = 30\text{mA}$ , $V_{IN} = 0\text{V}$     | 4.5V           | $T_A = -40^\circ\text{C}$ to 85°C        |      |      | 6        |          |
|            |                              | $I_O = -30\text{mA}$ , $V_{IN} = 2.4\text{V}$  |                |                                          |      |      | 8        |          |
|            |                              | $I_O = -30\text{mA}$ , $V_{IN} = 4.5\text{V}$  |                |                                          |      |      | 13       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 3.0V           | $T_A = 25^\circ\text{C}$                 |      | 5    | 8        |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 3.0\text{V}$  |                |                                          |      | 12   | 19       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 3.0V           | $T_A = -40^\circ\text{C}$ to 85°C        |      |      | 8        |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 3.0\text{V}$  |                |                                          |      |      | 19       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 2.3V           | $T_A = 25^\circ\text{C}$                 |      | 6    | 9        |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 2.3\text{V}$  |                |                                          |      | 16   | 24       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 2.3V           | $T_A = -40^\circ\text{C}$ to 85°C        |      |      | 9        |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 2.3\text{V}$  |                |                                          |      |      | 24       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 1.65V          | $T_A = 25^\circ\text{C}$                 |      | 8    | 12       |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 1.65\text{V}$ |                |                                          |      | 27   | 39       |          |
|            |                              | $I_O = 24\text{mA}$ , $V_{IN} = 0\text{V}$     | 1.65V          | $T_A = -40^\circ\text{C}$ to 85°C        |      |      | 12       |          |
|            |                              | $I_O = -24\text{mA}$ , $V_{IN} = 1.65\text{V}$ |                |                                          |      |      | 39       |          |

**PI5A3157**

| Parameters      | Description                                               | Test Conditions                                                 | Supply Voltage                              | Temp                                                                 | Min.          | Typ. | Max.          | Units         |
|-----------------|-----------------------------------------------------------|-----------------------------------------------------------------|---------------------------------------------|----------------------------------------------------------------------|---------------|------|---------------|---------------|
| $\Delta R_{ON}$ | On-Resistance Match Between Channels <sup>(1, 2, 3)</sup> | $I_A = -30\text{mA}$ , $V_{BN} = 3.15\text{V}$                  | 4.5V                                        | $T_A = 25^\circ\text{C}$                                             |               | 0.15 |               | $\Omega$      |
|                 |                                                           | $I_A = -24\text{mA}$ , $V_{BN} = 2.1\text{V}$                   | 3.0V                                        |                                                                      |               | 0.2  |               |               |
|                 |                                                           | $I_A = -8\text{mA}$ , $V_{BN} = 1.6\text{V}$                    | 2.3V                                        |                                                                      |               | 0.3  |               |               |
|                 |                                                           | $I_A = -4\text{mA}$ , $V_{BN} = 1.15\text{V}$                   | 1.65V                                       |                                                                      |               | 0.3  |               |               |
| $R_{ONF}$       | On-Resistance Flatness <sup>(1, 2, 4)</sup>               | $I_A = -30\text{mA}$ , $0 \leq V_{BN} \leq V_{DD}$              | 5.0V                                        | $T_A = 25^\circ\text{C}$                                             |               | 6    |               | $\Omega$      |
|                 |                                                           | $I_A = -24\text{mA}$ , $0 \leq V_{BN} \leq V_{DD}$              | 3.3V                                        |                                                                      |               | 12   |               |               |
|                 |                                                           | $I_A = -8\text{mA}$ , $0 \leq V_{BN} \leq V_{DD}$               | 2.5V                                        |                                                                      |               | 22   |               |               |
|                 |                                                           | $I_A = -4\text{mA}$ , $0 \leq V_{BN} \leq V_{DD}$               | 1.8V                                        |                                                                      |               | 90   |               |               |
| $V_{IH}$        | Input High Voltage                                        | Logic High Level                                                | $V_{DD} = 1.65\text{V}$ to $1.95\text{V}$   | $T_A = 25^\circ\text{C}$ & $-40^\circ\text{C}$ to $85^\circ\text{C}$ | 0.75 $V_{DD}$ |      |               | V             |
|                 |                                                           |                                                                 | $V_{DD} = 2.3\text{V}$ to $5.5\text{V}$     |                                                                      | 0.7 $V_{DD}$  |      |               |               |
| $V_{IL}$        | Input Low Voltage                                         | Logic Low Level                                                 | $V_{DD} = 1.65\text{V}$ to $1.95\text{V}$   |                                                                      |               |      | 0.25 $V_{DD}$ |               |
|                 |                                                           |                                                                 | $V_{DD} = 2.3\text{V}$ to $5.5\text{V}$     |                                                                      |               |      | 0.25 $V_{DD}$ |               |
|                 | Input Leakage Current                                     | $0 \leq V_{IN} \leq 5.5\text{V}$                                | $V_{DD} \leq 0\text{V} \leq 5.5\text{V}$    | $T_A = 25^\circ\text{C}$                                             |               |      | $\pm 0.1$     | $\mu\text{A}$ |
|                 |                                                           |                                                                 |                                             | $T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$                      |               |      | $\pm 1.0$     |               |
| $I_{OFF}$       | OFF State Leakage Current                                 | $0 \leq V_{IN} \leq 5.5\text{V}$                                | $V_{DD} \leq 1.65\text{V} \leq 5.5\text{V}$ | $T_A = 25^\circ\text{C}$                                             |               |      | $\pm 0.1$     |               |
|                 |                                                           |                                                                 |                                             | $T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$                      |               |      | $\pm 10$      |               |
| $I_{CC}$        | Quiescent Supply Current                                  | All Channels ON or OFF, $V_{IN} = V_{DD}$ or GND, $I_{OUT} = 0$ | $V_{DD} = 5.5\text{V}$                      | $T_A = 25^\circ\text{C}$                                             |               |      | 1             | $\mu\text{A}$ |
|                 |                                                           |                                                                 |                                             | $T_A = -40^\circ\text{C}$ to $85^\circ\text{C}$                      |               |      | 10            |               |

**Notes:**

1. Measured by voltage drop between A and B pins at the indicated current through the device. On-Resistance is determined by the lower of the voltages on two ports (A or B).
2. Parameter is characterized but not tested in production.
3.  $\Delta R_{ON} = R_{ON} \text{ max} - R_{ON} \text{ min}$ , measured at identical  $V_{DD}$ , temperature and voltage levels.
4. Flatness is defined as difference between maximum and minimum value of On-Resistance over the specified range of conditions.
5. Guaranteed by design.

**Capacitance<sup>(1)</sup>**

| Parameters   | Description            | Test Conditions           | Supply Voltage         | Temp                     | Min. | Typ. | Max. | Units |
|--------------|------------------------|---------------------------|------------------------|--------------------------|------|------|------|-------|
| $C_{IN}$     | Control Input          | $f = 1 \text{ MHz}^{(1)}$ | $V_{DD} = 5.0\text{V}$ | $T_A = 25^\circ\text{C}$ |      | 2.3  |      | pF    |
| $C_{IO-B}$   | For B Port, Switch OFF |                           |                        |                          |      | 6.5  |      |       |
| $C_{IOA-ON}$ | For A Port, Switch ON  |                           |                        |                          |      | 18.5 |      |       |

**Note:**

1.  $T_A = 25^\circ\text{C}$ ,  $f = 1\text{MHz}$ . Capacitance is characterized but not tested in production.

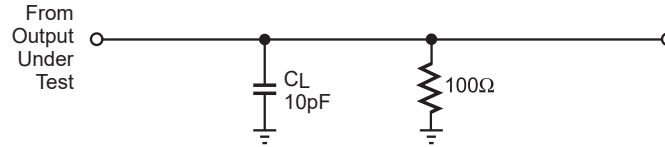
## Switch and AC Characteristics

| Parameters                           | Description                           | Test Conditions                                                                                                                     | Supply Voltage                                                                                                                         | Temp                                  | Min.                     | Typ.              | Max.                    | Units |
|--------------------------------------|---------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------|--------------------------|-------------------|-------------------------|-------|
| t <sub>PLH</sub><br>t <sub>PHL</sub> | Propagation Delay: A to Bn            | See test circuit diagram 1 and 2 V <sub>I</sub> Open <sup>(2)</sup>                                                                 | V <sub>DD</sub> = 2.3V to 2.7V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V                                     | T <sub>A</sub> = 25°C & -40°C to 85°C |                          | 1.2<br>0.8<br>0.3 |                         | ns    |
| t <sub>PZL</sub><br>t <sub>PZH</sub> | Output Enable Turn ON Time: A to Bn   | See test circuit diagram 1 and 2 V <sub>I</sub> = 2 V <sub>DD</sub> for t <sub>PZL</sub> , V <sub>I</sub> = 0V for t <sub>PZH</sub> | V <sub>DD</sub> = 1.65V to 1.95V<br>V <sub>DD</sub> = 2.3V to 2.7V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V | T <sub>A</sub> = 25°C                 | 7<br>3.5<br>2.5<br>1.7   |                   | 23<br>13<br>6.9<br>5.2  |       |
| t <sub>PZL</sub><br>t <sub>PZH</sub> | Output Enable Turn ON Time: A to Bn   | See test circuit diagram 1 and 2 V <sub>I</sub> = 2 V <sub>DD</sub> for t <sub>PZL</sub> , V <sub>I</sub> = 0V for t <sub>PZH</sub> | V <sub>DD</sub> = 2.5V<br>V <sub>DD</sub> = 3.3V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V                   | T <sub>A</sub> = 25°C & -40°C to 85°C |                          |                   | 24<br>14<br>7.6<br>5.7  |       |
| t <sub>PLZ</sub><br>t <sub>PHZ</sub> | Output Disable-Turn OFF Time: A to Bn | See test circuit diagram 1 and 2 V <sub>I</sub> = 2 V <sub>DD</sub> for t <sub>PLZ</sub> , V <sub>I</sub> = 0V for t <sub>PHZ</sub> | V <sub>DD</sub> = 1.65V to 1.95V<br>V <sub>DD</sub> = 2.3V to 2.7V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V | T <sub>A</sub> = 25°C                 | 3<br>2<br>1.5<br>0.8     |                   | 12.5<br>7<br>5<br>3.5   |       |
| t <sub>PLZ</sub><br>t <sub>PHZ</sub> | Output Disable-Turn OFF Time: A to Bn | See test circuit diagram 1 and 2 V <sub>I</sub> = 2 V <sub>DD</sub> for t <sub>PLZ</sub> , V <sub>I</sub> = 0V for t <sub>PHZ</sub> | V <sub>DD</sub> = 2.5V<br>V <sub>DD</sub> = 3.3V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V                   | T <sub>A</sub> = 25°C & -40°C to 85°C |                          |                   | 13<br>7.5<br>5.3<br>3.8 |       |
| t <sub>BM</sub>                      | Break Before Make Time                | See test circuit diagram 9. <sup>(1)</sup>                                                                                          | V <sub>DD</sub> = 2.5V<br>V <sub>DD</sub> = 3.3V<br>V <sub>DD</sub> = 3.0V to 3.6V<br>V <sub>DD</sub> = 4.5V to 5.5V                   | T <sub>A</sub> = 25°C & -40°C to 85°C | 0.5<br>0.5<br>0.5<br>0.5 |                   |                         |       |
| Q                                    | Charge Injection                      | C <sub>L</sub> = 0.1nF, V <sub>GEN</sub> = 0V, R <sub>GEN</sub> = 0Ω, See test circuit 4                                            | V <sub>DD</sub> = 5.0V<br>V <sub>DD</sub> = 3.3V                                                                                       | T <sub>A</sub> = 25°C                 |                          | 7<br>3            |                         | pC    |
| O <sub>IRR</sub>                     | Off Isolation                         | R <sub>L</sub> = 50Ω, V <sub>GEN</sub> = 0V, R <sub>GEN</sub> = 0Ω, See test circuit 5 <sup>(3)</sup>                               | V <sub>DD</sub> = 1.65V to 5.5V                                                                                                        | T <sub>A</sub> = 25°C                 |                          | -57               |                         | dB    |
| X <sub>TALK</sub>                    | Crosstalk Isolation                   | See test circuit 6                                                                                                                  | V <sub>DD</sub> = 1.65V to 5.5V                                                                                                        | T <sub>A</sub> = 25°C                 |                          | -54               |                         |       |
| f <sub>3dB</sub>                     | -3dB Bandwidth                        | See test circuit 9                                                                                                                  | V <sub>DD</sub> = 1.65V to 5.5V                                                                                                        | T <sub>A</sub> = 25°C                 |                          | 250               |                         | MHz   |

### Notes:

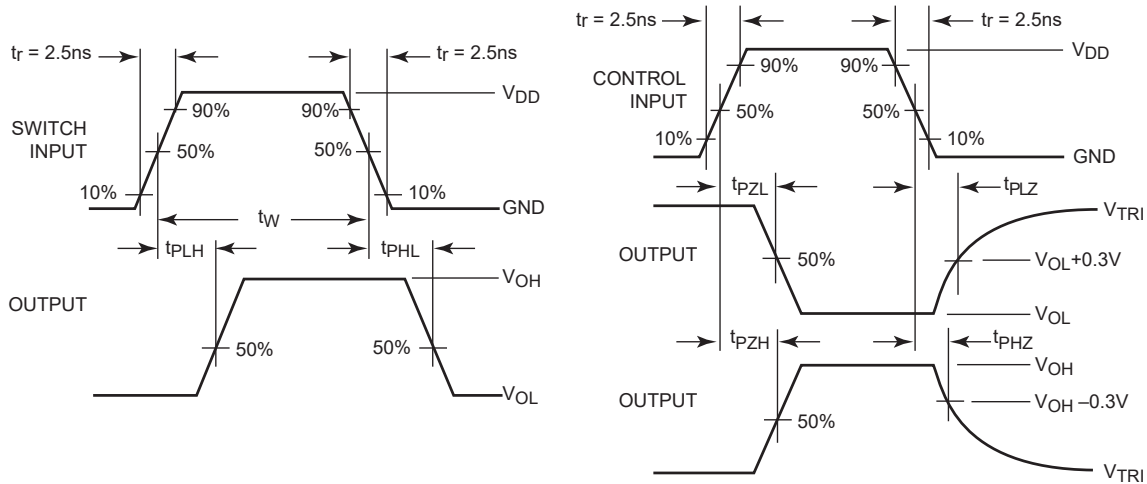
- Guaranteed by design.
- Guaranteed by design but not production tested. The device contributes no other propagation delay other than the RC delay of the switch On-Resistance and the 50pF load capacitance, when driven by an ideal voltage source with zero output impedance.
- Off Isolation = 20 Log<sub>10</sub> [ V<sub>A</sub> / V<sub>Bn</sub> ] and is measured in dB.

## Test Circuits and Timing Diagrams

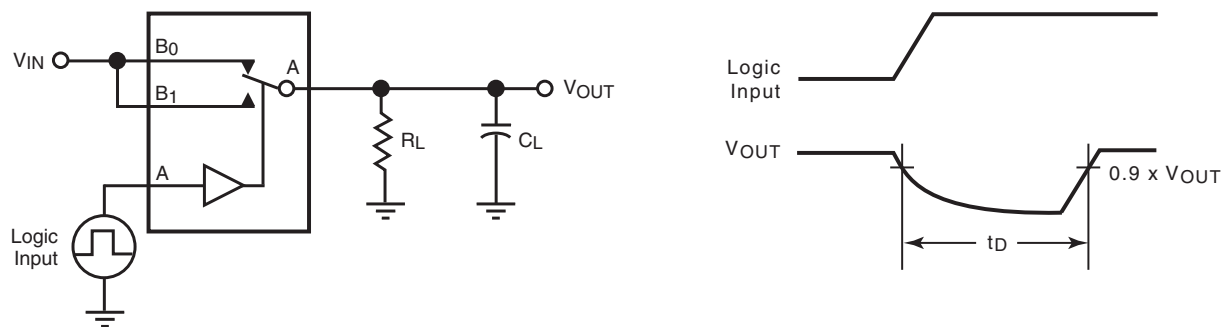


Notes: Input driven by 50Ω source terminated in 50Ω.  
CL includes load and stray capacitance.  
Input PRR = 1.0 MHz;  $t_w = 500\text{ns}$ .

**Figure 1. AC Test Circuit**

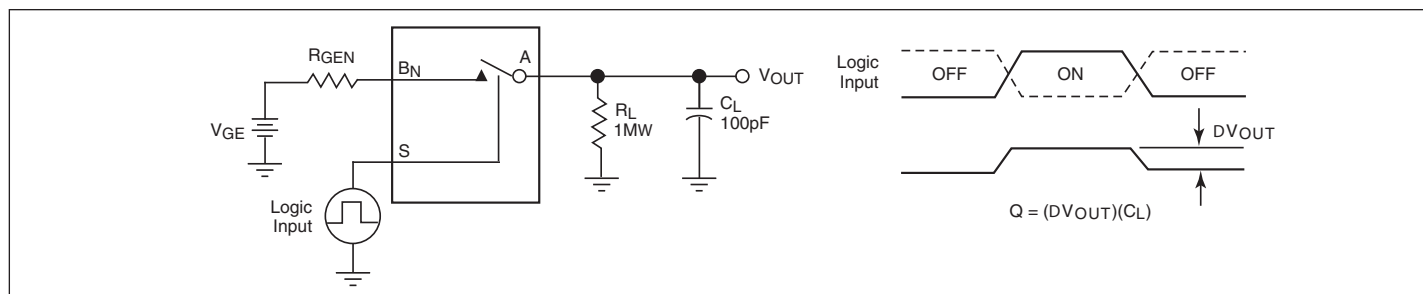


**Figure 2. AC Waveforms**

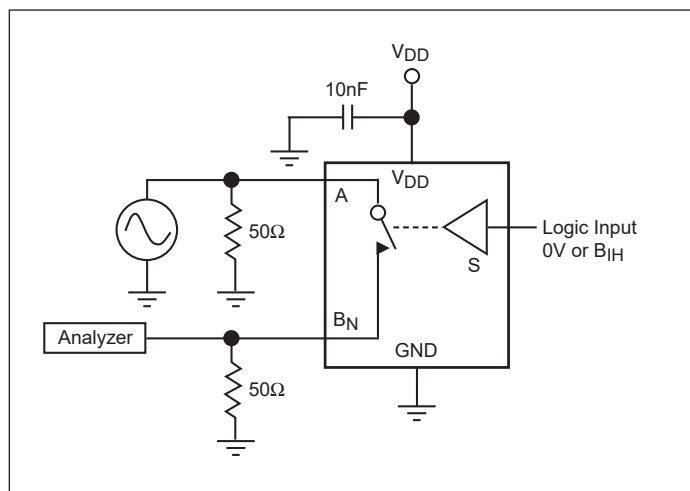


**Figure 3. Break Before Make Interval Timing**

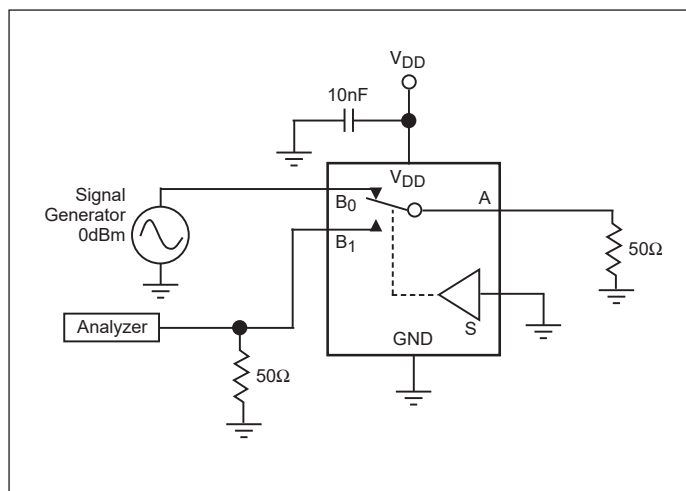
PI5A3157



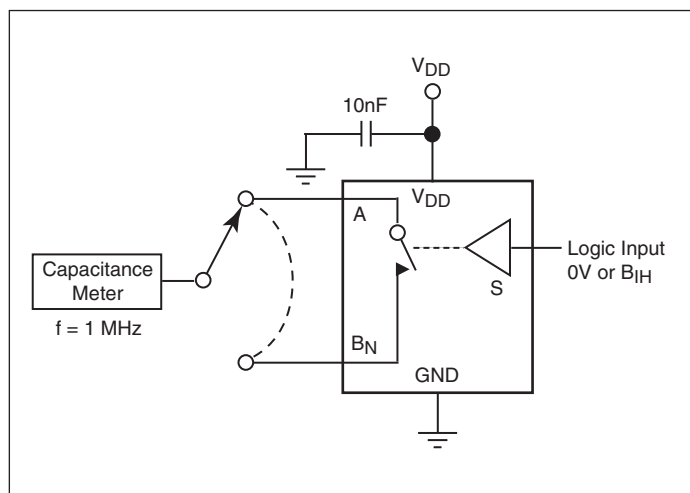
**Figure 4. Charge Injection Test**



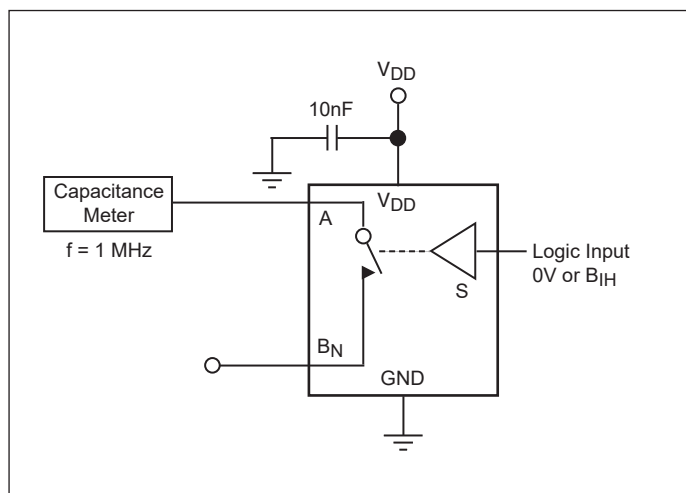
**Figure 5. Off Isolation**



**Figure 6. Crosstalk**

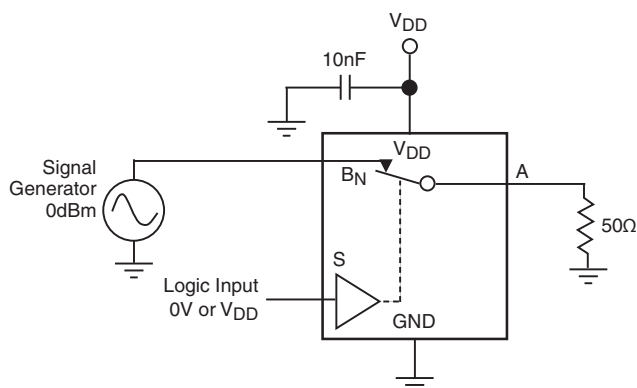


**Figure 7. Channel Off Capacitance**



**Figure 8. Channel On Capacitance**

**PI5A3157**



**Figure 9. Bandwidth**

## Part Marking

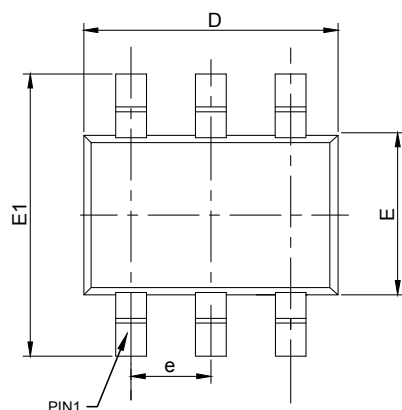
Top Mark:  $\bar{Z}MYW$   
Pin 1

Y: Date Code (Year)  
W: Date Code (Workweek)  
Bar above "W" means Cu wire

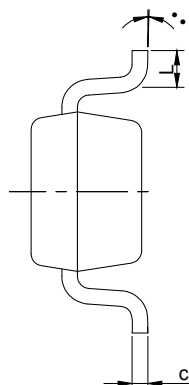
**PI5A3157**

## Packaging Mechanical

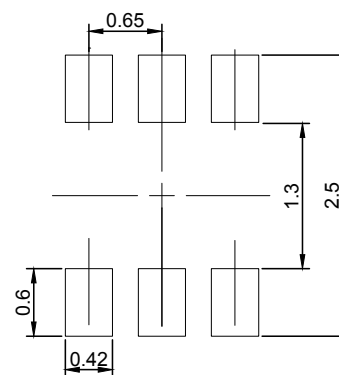
### 6-SC70 (C)



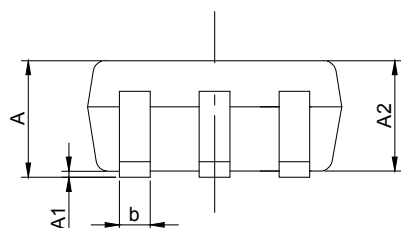
TOP VIEW



BOTTOM VIEW



RECOMMENDED LAND PATTERN (unit:mm)



SIDE VIEW

| PKG. DIMENSIONS(MM) |          |      |
|---------------------|----------|------|
| SYMBOL              | Min      | Max  |
| A                   | -        | 1.10 |
| A1                  | 0.00     | 0.10 |
| A2                  | 0.70     | 1.00 |
| b                   | 0.15     | 0.40 |
| c                   | 0.08     | 0.22 |
| D                   | 1.80     | 2.20 |
| E                   | 1.10     | 1.40 |
| E1                  | 1.80     | 2.45 |
| e                   | 0.65 BSC |      |
| L                   | 0.26     | 0.46 |
| θ                   | 0°       | 8°   |

**Notes:**

1. Comply with MO-203C/AB, except b Max, D Min and D Max.
2. PACKAGE OUTLINE DIMENSIONS DO NOT INCLUDE MOLD FLASH AND METAL BURR
3. LAND PATTERN REFERENCE DIODES SOT363 PACKAGE INFORMATION.



DATE: 12/16/21

**DESCRIPTION: 6-Pin, SOT363 (SC70)**
**PACKAGE CODE: C (C6)**
**DOCUMENT CONTROL#: PD-1902**
**REVISION: D**

21-1534

For latest package info.

 please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

## Ordering Information

| Ordering Code | Packaging Code | Package Description  | Top Mark |
|---------------|----------------|----------------------|----------|
| PI5A3157CEX   | C              | 6-pin, SOT363 (SC70) | ZM       |

**Notes:**

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. E = Pb-free and Green
5. X suffix = Tape/Reel

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